

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	(US-6225656-\$).did.	USPAT	OR	OFF	2009/01/04 22:07
L2	1	L1 and (oxide nitride SiN).detx.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:07
L5	1	(US-20040089894-\$ or US-20030178663-\$).did. or (US-6673672-\$).did.	US-PGPUB; USPAT	OR	OFF	2009/01/04 22:12
L6	1	L5 and (first adj insulating and first adj capacitor and oxide and (nitride SiN)).detx.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:12
L7	1	L5 and (second adj insulating and second adj capacitor and oxide and (nitride SiN)).detx.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:13
L8	0	L5 and (second adj insulating and second adj capacitor) with oxide with carbon.detx.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:16
L9	0	L5 and (second adj insulating and second adj capacitor) with oxide.detx. and carbon.detx.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:18
L10	1	L5 and (second adj insulating and second adj capacitor) with oxide.detx.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:19
L11	1	10 and carbon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:19

L12	184	carbon with content with insulating adj film	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/04 22:29
L13	67	L12 and capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/04 22:29
L14	117	L12 not L13	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/04 22:29
L15	51	mitsubishi and adhesi \$7	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L16	8	mitsubishi and adhesi \$7 and carbon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L17	128	ohto and adhesi\$7 and carbon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L18	70	(usami ohto) and adhesi \$7 with carbon	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L19	5	"6784485"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L20	3470	silicon adj (oxide dioxide) with dielectric with carbon	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2009/01/04 22:29

L21	793	L20 and teos	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2009/01/04 22:29
L22	13000	((257/295-306) or (361/302-305,310-313)). CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/01/04 22:29
L23	482	L22 and (silane or carbon) with (insulating insulation insulated dielectric)	US-PGPUB; USPAT	OR	ON	2009/01/04 22:29
L24	35	second capacitor protection	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L25	34205	carbon and capacitor	US-PGPUB; USPAT	OR	OFF	2009/01/04 22:29
L26	111	"5,554,570"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L27	885	(low-k or low dielectric constant) with carbon with silicon (dioxide or oxide) and barrier	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L28	12	Sashida and carbon and capacitor	US-PGPUB; USPAT	OR	OFF	2009/01/04 22:29
L29	4903	(chemical vapor deposition or CVD) and bias voltage and carbon	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L30	596	ferroelectric capacitor and (barrier adj dielectric or diffusion adj barrier)	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L31	40	"6509601"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L32	39	RI.IN. AND CAPACITOR AND FERROELECTRIC	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L33	277	(chemical vapor deposition or CVD) and bias voltage and carbon content	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L34	277	carbon and L33	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L35	105	L26 and (silane or carbon)	US-PGPUB; USPAT	OR	ON	2009/01/04 22:29

L36	5182	RI.IN.	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L37	111	"5,554,570"	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L38	90	L37 and (silane or carbon) with plasma	US-PGPUB; USPAT	OR	ON	2009/01/04 22:29
L39	66	carbon same teos same silane and carbon near (content composition concentratation)	US-PGPUB; USPAT	OR	ON	2009/01/04 22:29
L40	694	L21 and plasma	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2009/01/04 22:29
L41	19	ferroelectric capacitor and (barrier adj dielectric or diffusion adj barrier near dielectric)	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L42	44	L40 and plasma with teos and cvd with ozone with teos	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2009/01/04 22:29
L43	32	ABDELGADIR	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L44	23	SAMSUNG AND BLOCKING AND HYDROGEN AND FERROELECTRIC	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L45	17	Sashida and carbon and insulating adj film	US-PGPUB; USPAT	OR	OFF	2009/01/04 22:29
L46	2206	(257/306).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/01/04 22:29
L47	1835	L22 and (silane or carbon)	US-PGPUB; USPAT	OR	ON	2009/01/04 22:29
L48	18	"5,554,559" and hydrogen	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L49	183	dielectric and L33	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L50	339	L20 and carbon adj content	US-PGPUB; USPAT; EPO; DERWENT; IBM_TDB	OR	ON	2009/01/04 22:29

L51	8	(low-k or low dielectric constant) with carbon with silicon (dioxide or oxide)and pzt	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L52	13	plate adj capacitor and fourth adj interlayer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/01/04 22:29
L53	65	dielectric adj constant with carbon content with oxide	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L54	59	(chemical vapor deposition or CVD) and bias voltage and carbon content with oxide	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L55	467	carbon same teos same silane	US-PGPUB; USPAT	OR	ON	2009/01/04 22:29
L56	617	(low-k or low dielectric constant) with carbon near2 silicon (dioxide or oxide)	US-PGPUB; USPAT	ADJ	OFF	2009/01/04 22:29
L57	682	capacitor and fourth adj interlayer	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29
L58	8	("5475248" "5481490" "5510651" "5780351" "6184927" "6200821" "6355952" "6495879"). PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/01/04 22:29
L59	6	(Hikosaka near2 Yukinobu Ozaki near2 Yasutaka Takai near2 Kazuaki).in. and ferroelectric and @pd<"20030101"	US-PGPUB; USPAT; USOCR	OR	OFF	2009/01/04 22:29
L60	41	second capacitor protection	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2009/01/04 22:29
L61	10	L28 and plug and hole	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/01/04 22:29

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